

NCE Automotive N-Channel Super Trench II Power MOSFET

Description

The NCEAP025N60AG uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

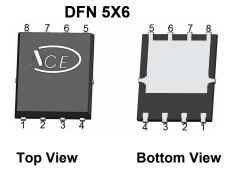
General Features

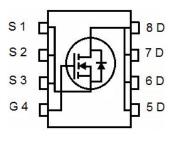
V_{DS} =60V,I_D =185A

 $R_{\text{DS(ON)}}\text{=}2.0\text{m}\Omega$ (typical) @ $V_{\text{GS}}\text{=}10\text{V}$

 $R_{DS(ON)}$ =2.5m Ω (typical) @ V_{GS} =4.5V

- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP025N60AG	NCEAP025N60AG	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	185	А
Drain Current-Continuous(Tc=100℃)	I _D (100°C)	130	А
Pulsed Drain Current	I _{DM}	740	А
Maximum Power Dissipation	P _D	175	W
Derating factor		1.16	W/°C
Single pulse avalanche energy (Note 1)	Eas	540	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	Rejc	0.85	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)



http://www.ncepower.com

NCEAP025N60AG

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.4	V
D : 0		V _{GS} =10V, I _D =20A	-	2.0	2.5	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	-	2.5	3.7	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	45	-	-	S
Dynamic Characteristics			'			
Input Capacitance	C _{lss}	.,	-	6540	-	PF
Output Capacitance	Coss	V_{DS} =30V, V_{GS} =0V,	-	900	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	65	-	PF
Switching Characteristics (Note 2)	,		'			
Turn-on Delay Time	t _{d(on)}		-	16	-	nS
Turn-on Rise Time	t _r	V_{DD} =30 V , I_D =20 A	-	9	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =4.7 Ω	-	58	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	.,	-	99.5		nC
Gate-Source Charge	Q _{gs}	V _{DS} =30V,I _D =20A,	-	16.2		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	14.4		nC
Drain-Source Diode Characteristics	1					
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	185	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	56	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	80	-	nC

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=30V,VG=10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.





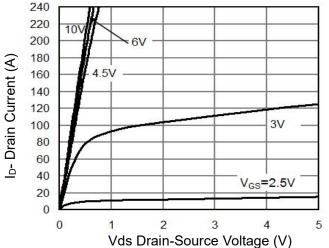


Figure 1 Output Characteristics

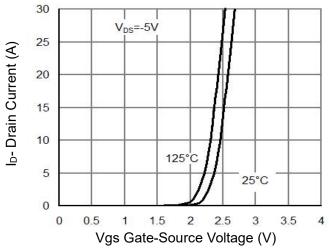
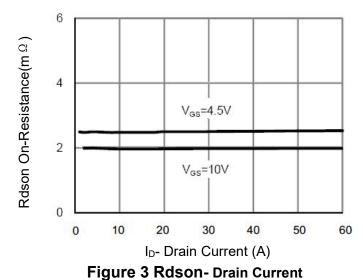


Figure 2 Transfer Characteristics



2.2 2 Normalized On-Resistance V_{GS}=10V I_D=20A 1.8 1.6 1.4 V_{GS}=4.5V I_D=20A 1.2

Figure 4 Rdson-JunctionTemperature

T_J-Junction Temperature(°C)

75

100

125

150

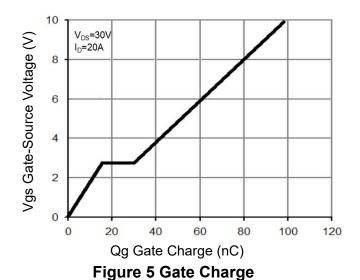
175

0.8

0

25

50



1.0E+02 Is- Reverse Drain Current (A) 1.0E+01 1.0E+00 1.0E-01 125° 1.0E-02 1.0E-03 25° 1.0E-04 1.0E-05 0.8 0.0 0.2 0.4 0.6 1.0 1.2 Vsd Source-Drain Voltage (V)

Figure 6 Source- Drain Diode Forward



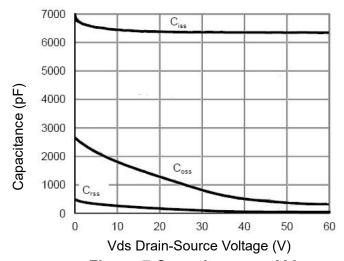


Figure 7 Capacitance vs Vds

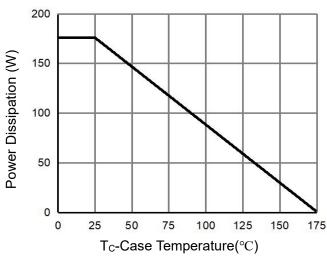


Figure 9 Power De-rating

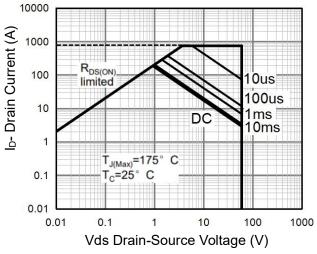


Figure 8 Safe Operation Area (Note3)

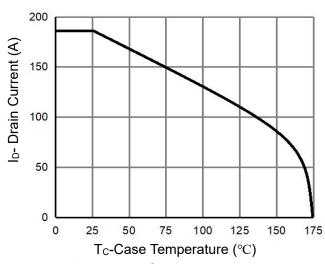


Figure 10 Current De-rating

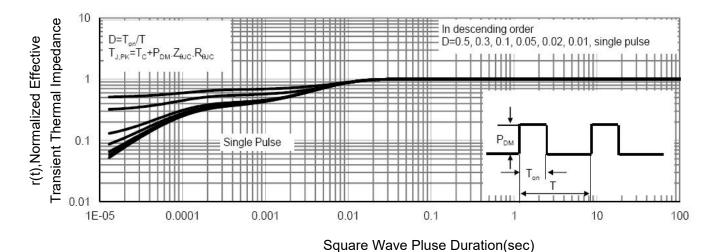
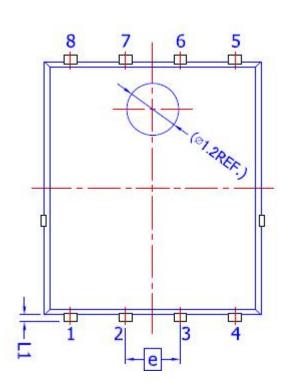
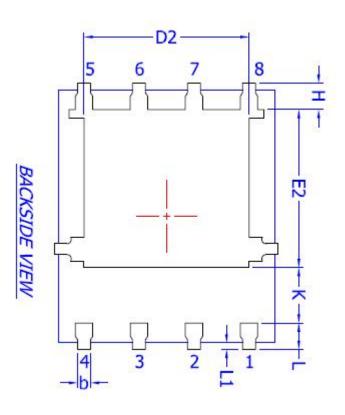


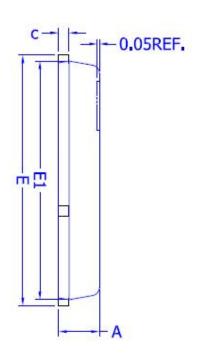
Figure 11 Normalized Maximum Transient Thermal Impedance

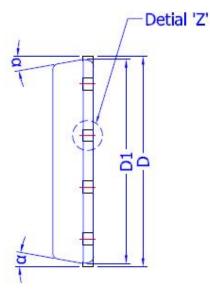


DFN5X6-8L Package Information









DIM.	MIL	LIMETE	RS		
	MIN.	NOM.	MAX.		
Α	0.90	1.00	1.10		
A1	0	-	0.05		
Ь	0.30	0.40	0.50		
С	0.20	0.25	0.30		
D	5.15 BSC				
D1	5.00 BSC				
D2	3.76	3.81	3.86		
E	6.15 BSC				
E1	5.80	5.85	5.90		
E2	3.45	3.65	3.85		
е	1.27 BSC				
Н	0.51	0.61	0.71		
K	1.10	(=)	-		
L	0.51	0.61	0.71		
L1	0.08	0.15	0.23		
α	10°	110	12°		

http://www.ncepower.com

NCEAP025N60AG

Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2022. Specifications and information herein are subject to change without notice.

单击下面可查看定价,库存,交付和生命周期等信息

>>NCEPOWER(无锡新洁能)